

1PS302

Dual high-speed switching diode Rev. 6 — 23 July 2012

Product data sheet

1. **Product profile**

1.1 General description

Dual high-speed switching diode, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Repetitive peak reverse voltage: $V_{RRM} \le 85 V$
- Reverse voltage: V_R ≤ 80 V
- AEC-Q101 qualified

- Low capacitance: C_d ≤ 1.5 pF
- Repetitive peak forward current: $I_{FRM} \leq 500~mA$
- Very small SMD plastic package

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current		[1]			
			[2] _	-	200	mA
			[3] _	-	170	mA
I _R	reverse current	$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	80	V
t _{rr}	reverse recovery time		<u>[4]</u> _	-	4	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



^[2] Single diode loaded.

^[3] Double diode loaded.

^[4] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

Dual high-speed switching diode

2. Pinning information

Table 2. Pinning

Table 2.	Filling		
Pin	Description	Simplified outline	Graphic symbol
1	anode		
2	cathode	3	3
3	cathode (diode 1), anode (diode 2)	1 2	
			006aaa763

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
1PS302	SC-70	plastic surface-mounted package; 3 leads	SOT323

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
1PS302	C*3

^{[1] * =} placeholder for manufacturing site code

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	85	V
V_R	reverse voltage		-	80	V
I _F	forward current		<u>[1]</u>		
			[2] _	200	mA
			[3] _	170	mA
I _{FRM}	repetitive peak forward current	$t_p \leq 0.5~\mu\text{s}; \\ \delta \leq 0.25$	-	500	mA
I _{FSM}	non-repetitive peak forward	square wave	<u>[4]</u>		
	current	t _p = 1 μs	-	4	А
		t _p = 1 s	-	0.5	А

1PS302

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2012. All rights reserved.

Dual high-speed switching diode

 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> _	300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	415	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	200	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V _F	forward voltage	I _F = 1 mA	-	610	-	mV
	I _F = 10 mA	-	740	-	mV	
		I _F = 50 mA	-	-	1.0	V
		I _F = 100 mA	-	-	1.2	V
I _R reverse current	reverse current	V _R = 25 V	-	-	30	nA
		V _R = 80 V	-	-	0.5	μΑ
		V _R = 25 V; T _j = 150 °C	-	-	30	μΑ
		V _R = 80 V; T _j = 150 °C	-	-	100	μΑ
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns
V_{FR}	forward recovery voltage		<u>[2]</u> _	-	1.75	V

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

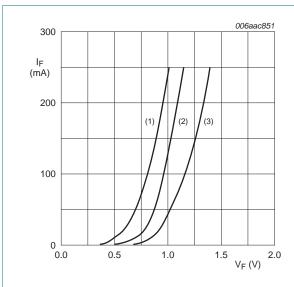
^[2] Single diode loaded.

^[3] Double diode loaded.

^[4] $T_j = 25$ °C before surge.

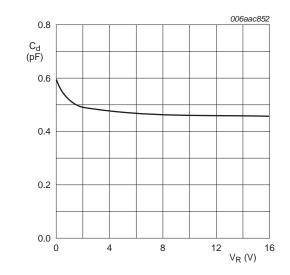
^[2] When switched from $I_F = 10$ mA; $t_r = 20$ ns.

Dual high-speed switching diode



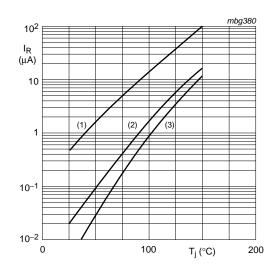
- (1) $T_i = 150 \,^{\circ}\text{C}$; typical values
- (2) $T_i = 25 \,^{\circ}C$; typical values
- (3) $T_i = 25 \, ^{\circ}C$; maximum values

Fig 1. Forward current as a function of forward voltage



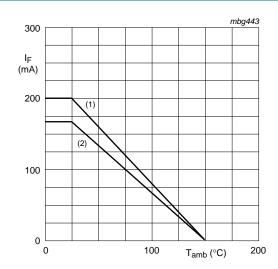
 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values



- (1) $V_R = 80 \text{ V}$; maximum values
- (2) V_R = 80 V; typical values
- (3) $V_R = 25 V$; typical values

Fig 2. Reverse current as a function of junction temperature



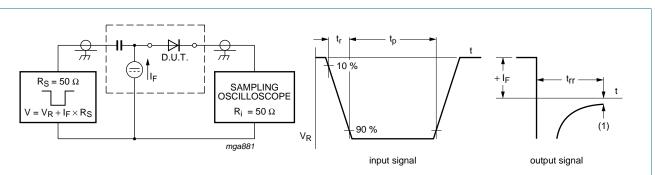
FR4 PCB, standard footprint

- (1) single diode loaded
- (2) double diode loaded

Fig 4. Forward current as a function of ambient temperature; derating curves

Dual high-speed switching diode

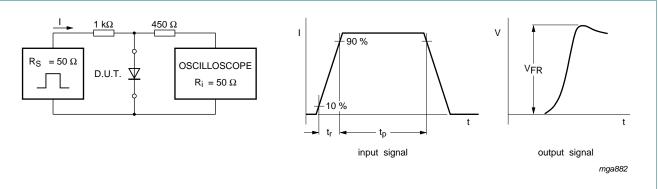
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

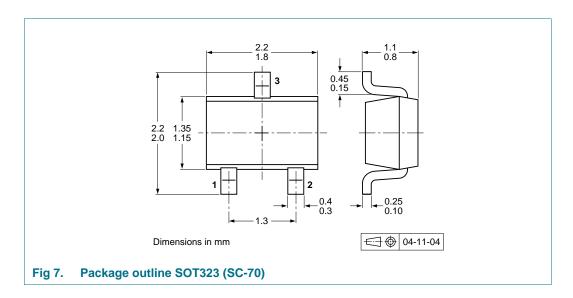
Fig 6. Forward recovery voltage test circuit and waveforms

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Dual high-speed switching diode

9. Package outline



10. Packing information

Table 8. Packing methods

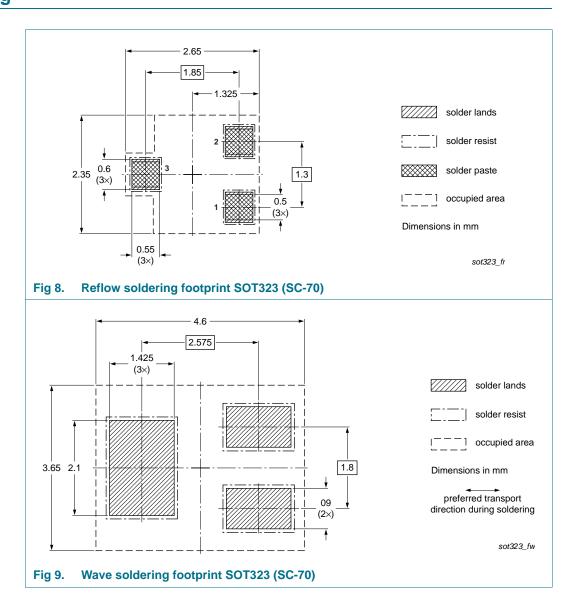
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing q	uantity
			3000	10000
1PS302	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

^[1] For further information and the availability of packing methods, see Section 14.

Dual high-speed switching diode

11. Soldering



Dual high-speed switching diode

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
1PS302 v.6	20120723	Product data sheet	-	1PS302 v.5
Modifications:	 Section 2 "Pir 	nning information": correcte	d	
1PS302 v.5	20111116	Product data sheet	-	1PS302 v.4
1PS302 v.4	19990506	Product data sheet	-	1PS302 v.3
1PS302 v.3	19961004	Product specification	-	1PS302 v.2
1PS302 v.2	19960903	Product specification	-	1PS302 v.1
1PS302 v.1	19960403	Product specification	-	-

Dual high-speed switching diode

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

1PS302

Dual high-speed switching diode

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

Dual high-speed switching diode

15. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 2
6	Thermal characteristics 3
7	Characteristics 3
8	Test information 5
8.1	Quality information 5
9	Package outline 6
10	Packing information 6
11	Soldering 7
12	Revision history 8
13	Legal information 9
13.1	Data sheet status 9
13.2	Definitions 9
13.3	Disclaimers
13.4	Trademarks 10
14	Contact information 10
15	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP:

1PS302,115